

To all our customers

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Renesas Technology Corp.  
Customer Support Dept.  
April 1, 2003

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# HD74LVCZ16240A

16-bit Buffers / Line Drivers with 3-state Outputs



ADE-205-231 (Z)

1st. Edition  
February 1999

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## Description

The HD74LVCZ16240A has sixteen inverter drivers with three state outputs in a 48 pin package. This device is an inverting buffer and has four active low enables ( $\overline{1G}$  to  $\overline{4G}$ ). Each enable independently controls four buffers.

When  $V_{CC}$  is between 0 and 1.5 V, the device is in the high impedance state during power up or power down.

Low voltage and high speed operation is suitable at battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

## Features

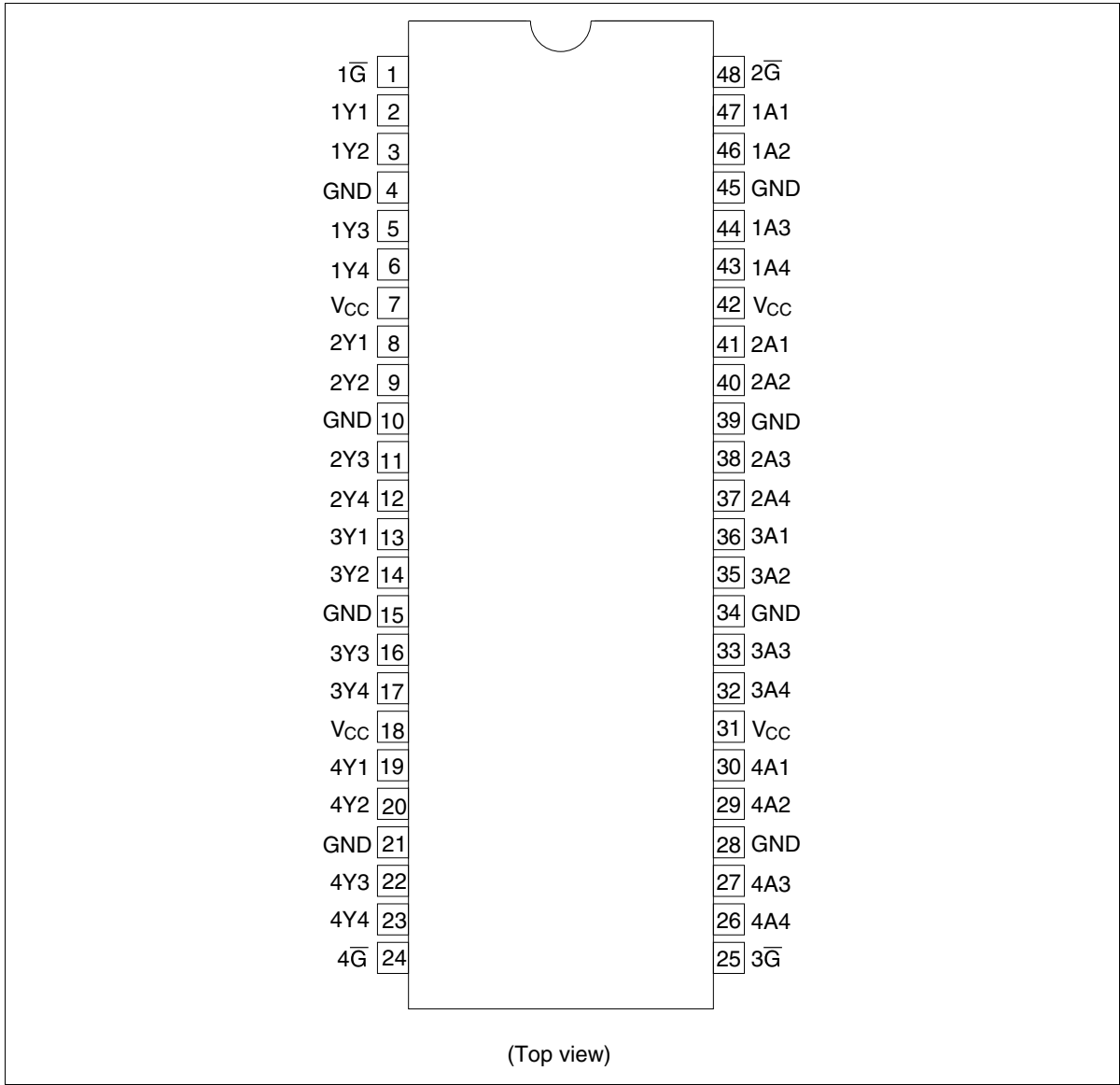
- $V_{CC} = 2.7$  to  $5.5$  V
- All inputs  $V_{IH}$  (Max) =  $5.5$  V (@  $V_{CC} = 0$  to  $5.5$  V)
- All outputs  $V_O$  (Max) =  $5.5$  V (@  $V_{CC} = 0$  V or output off state)
- Typical  $V_{OL}$  ground bounce  $< 0.8$  V (@  $V_{CC} = 3.3$  V,  $T_a = 25^\circ\text{C}$ )
- Typical  $V_{OH}$  undershoot  $> 2.0$  V (@  $V_{CC} = 3.3$  V,  $T_a = 25^\circ\text{C}$ )
- High impedance state during power up and power down
- Power off disables outputs, permitting live insertion
- High output current  $\pm 24$  mA (@  $V_{CC} = 3.0$  to  $5.5$  V)

Function Table

Inputs		Output Y
$\overline{\text{G}}$	A	
H	X	Z
L	H	L
L	L	H

H : High level  
L : Low level  
X : Immaterial  
Z : High impedance

Pin Arrangement



**Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	$V_{CC}$	-0.5 to 7.0	V	
Input voltage	$V_I$	-0.5 to 7.0	V	
Output voltage	$V_O$	-0.5 to 7.0	V	Output "Z" or $V_{CC}$ : OFF
		-0.5 to $V_{CC}+0.5$		Output "H" or "L"
Input diode current	$I_{IK}$	-50	mA	$V_I < 0$
Output diode current	$I_{OK}$	-50	mA	$V_O < 0$
Output current	$I_O$	$\pm 50$	mA	
$V_{CC}$ , GND current	$I_{CC}$ or $I_{GND}$	$\pm 100$	mA	
Storage temperature	$T_{stg}$	-65 to 150	°C	

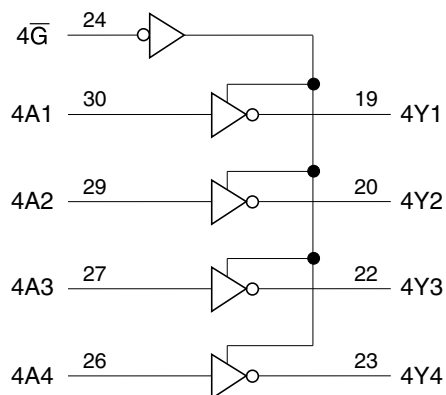
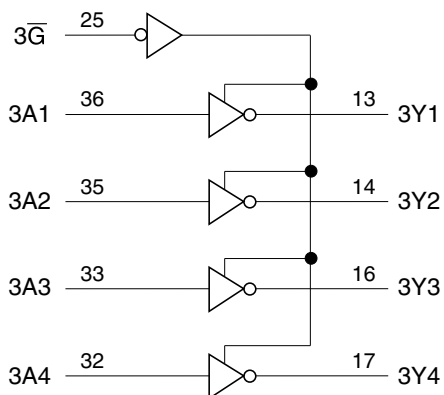
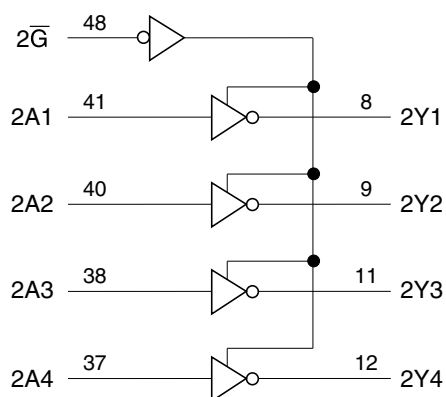
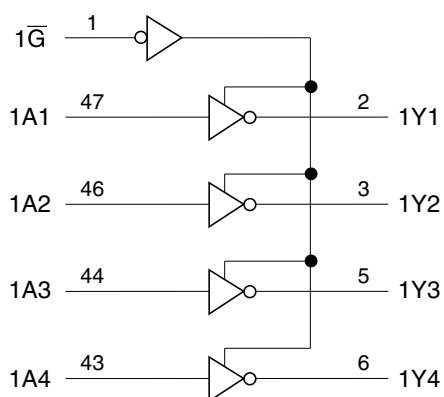
Note: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

**Recommended Operating Conditions**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	$V_{CC}$	2.7 to 5.5	V	At operation
Input voltage	$V_I$	0 to 5.5	V	
Output voltage	$V_O$	0 to 5.5	V	Output "Z" or $V_{CC}$ : OFF
		0 to $V_{CC}$		Output "H" or "L"
Output current	$I_{OH}$	-12	mA	$V_{CC} = 2.7$ V
		-24 <sup>*1</sup>		$V_{CC} = 3.0$ to 5.5 V
	$I_{OL}$	12		$V_{CC} = 2.7$ V
		24 <sup>*1</sup>		$V_{CC} = 3.0$ to 5.5 V
Input rise / fall time	$t_r, t_f$	0 to 6	ns / V	
Operating temperature	$T_a$	-40 to +85	°C	

Note: 1. Duty cycle  $\leq 50\%$

# Logic Diagram



## Electrical Characteristics (Ta = -40 to 85°C)

Item	Symbol	V <sub>cc</sub> (V)	Min	Typ	Max	Unit	Test Conditions
Input voltage	V <sub>IH</sub>	2.7 to 3.6	2.0	—	—	V	
		4.5 to 5.5	V <sub>cc</sub> ×0.7	—	—		
	V <sub>IL</sub>	2.7 to 3.6	—	—	0.8		
		4.5 to 5.5	—	—	V <sub>cc</sub> ×0.3		
Output voltage	V <sub>OH</sub>	2.7 to 5.5	V <sub>cc</sub> -0.2	—	—	V	I <sub>OH</sub> = -100 μA
		2.7	2.2	—	—		I <sub>OH</sub> = -12 mA
		3.0	2.4	—	—		
		3.0	2.2	—	—		I <sub>OH</sub> = -24 mA
		4.5	3.8	—	—		
	V <sub>OL</sub>	2.7 to 5.5	—	—	0.2		I <sub>OL</sub> = 100 μA
		2.7	—	—	0.4		I <sub>OL</sub> = 12 mA
		3.0	—	—	0.55		I <sub>OL</sub> = 24 mA
		4.5	—	—	0.55		
Input current	I <sub>IN</sub>	0 to 5.5	—	—	±5	μA	V <sub>IN</sub> = 0 to 5.5 V
Off state output current	I <sub>OZ</sub>	2.7 to 5.5	—	—	±5	μA	V <sub>OUT</sub> = 0 to 5.5 V
	I <sub>OZPU</sub>	0 to 1.5	—	—	±5		V <sub>OUT</sub> = 0.5 to 5.5 V,
	I <sub>OZPD</sub>	1.5 to 0	—	—	±5		Output enable = don't care
Output leak current	I <sub>OFF</sub>	0	—	—	±5	μA	V <sub>IN</sub> or V <sub>O</sub> = 5.5 V
Quiescent supply current	I <sub>CC</sub>	2.7 to 3.6	—	—	225	μA	V <sub>IN</sub> = 3.6 to 5.5 V <sup>1)</sup> , I <sub>O</sub> = 0
		2.7 to 5.5	—	—	350		V <sub>IN</sub> = V <sub>CC</sub> or GND
	ΔI <sub>CC</sub>	2.7 to 3.6	—	—	500		V <sub>IN</sub> = one input at (V <sub>CC</sub> -0.6) V, other inputs at V <sub>CC</sub> or GND
Input capacitance	C <sub>IN</sub>	3.3	—	4.1	—	pF	V <sub>IN</sub> = V <sub>CC</sub> or GND
Output capacitance	C <sub>O</sub>	3.3	—	8.1	—	pF	V <sub>OUT</sub> = V <sub>CC</sub> or GND

Note: 1. This applies in the disabled state only.



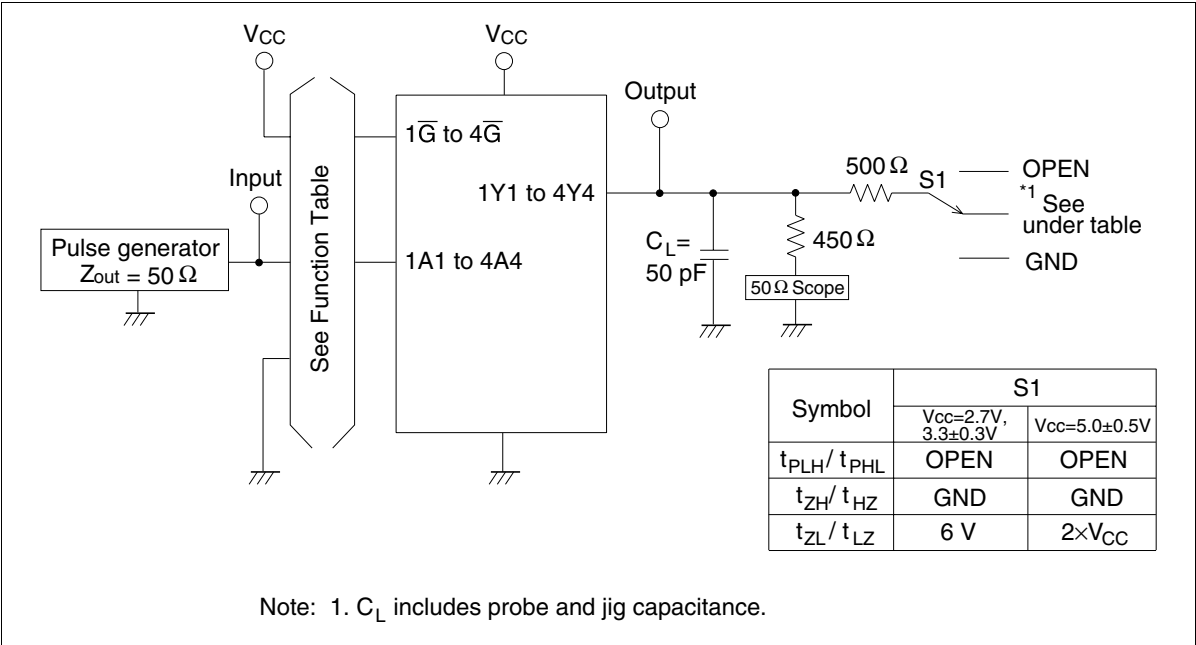
Switching Characteristics (Ta = -40 to 85°C)

Item	Symbol	V <sub>cc</sub> (V)	Min	Typ	Max	Unit	FROM (Input)	TO (Output)
Propagation delay time	t <sub>PLH</sub>	2.7	—	—	5.3	ns	A	Y
	t <sub>PHL</sub>	3.3±0.3	1.1	—	4.7			
		5.0±0.5	—	—	4.2			
Output enable time	t <sub>ZH</sub>	2.7	—	—	6.2	ns	$\overline{\text{G}}$	Y
	t <sub>ZL</sub>	3.3±0.3	1.0	—	5.0			
		5.0±0.5	—	—	4.5			
Output disable time	t <sub>HZ</sub>	2.7	—	—	7.4	ns	$\overline{\text{G}}$	Y
	t <sub>LZ</sub>	3.3±0.3	1.8	—	6.3			
		5.0±0.5	—	—	4.7			
Between output pin skew <sup>*1</sup>	t <sub>OSLH</sub>	2.7	—	—	—	ns		
	t <sub>OSHL</sub>	3.3±0.3	—	—	1.0			
		5.0±0.5	—	—	1.0			

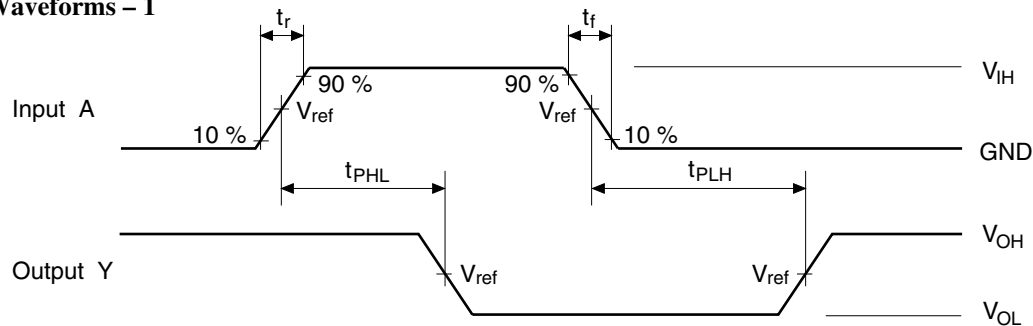
Note : 1. This parameter is characterized but not tested.

$t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

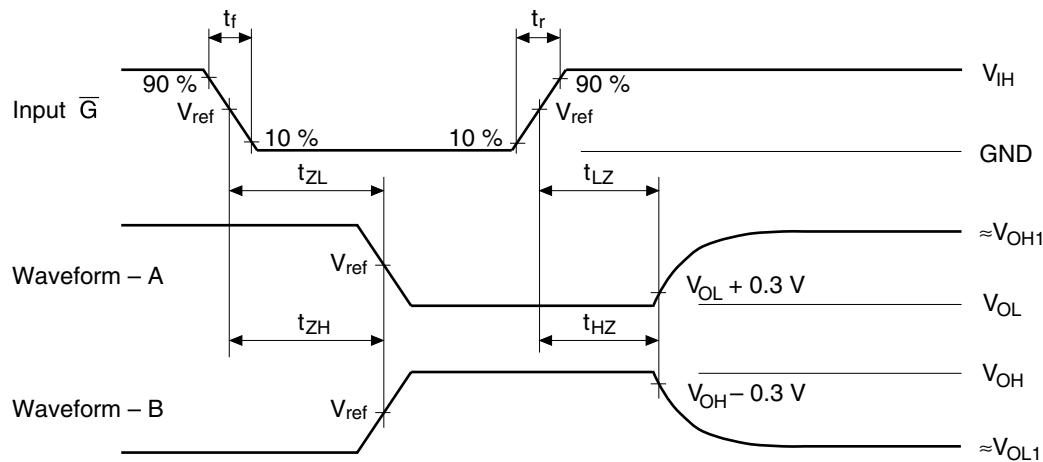
Test Circuit



• Waveforms – 1



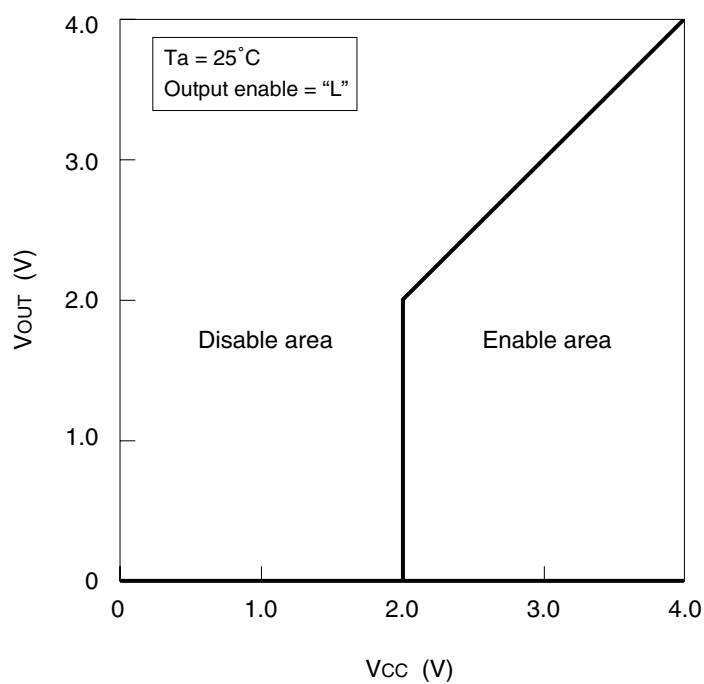
• Waveforms – 2



TEST	$V_{CC}=2.7V, 3.3\pm0.3V$	$V_{CC}=5.0\pm0.5V$
$V_{IH}$	2.7 V	$V_{CC}$
$V_{ref}$	1.5 V	$50\%V_{CC}$
$V_{OH1}$	3 V	$V_{CC}$
$V_{OL1}$	GND	GND

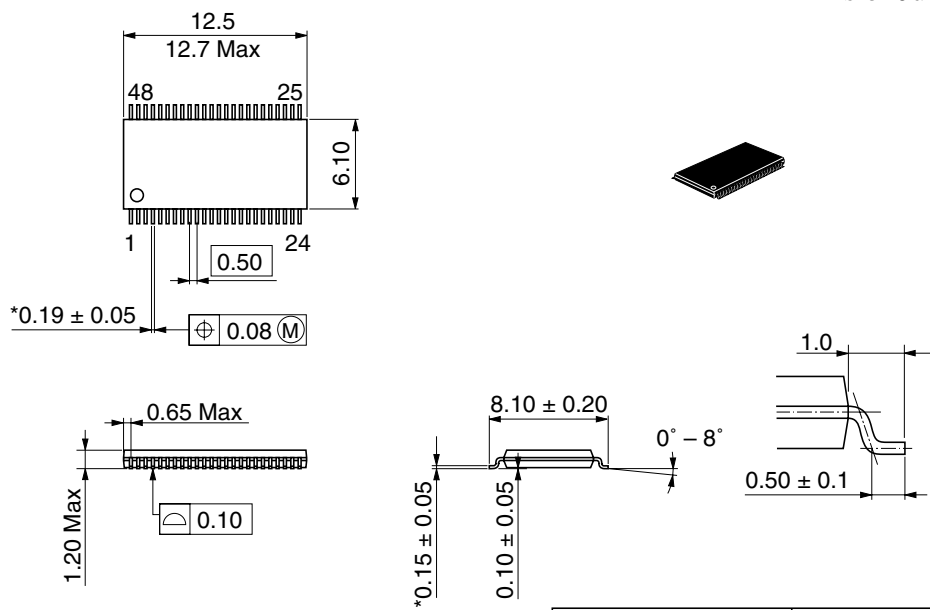
- Notes:
1. Input waveform : PRR = 10 MHz, duty cycle 50%,  $t_r = 2.5$  ns,  $t_f = 2.5$  ns
  2. Waveform – A shows input conditions such that the output is “L” level when enabled by the output control.
  3. Waveform – B shows input conditions such that the output is “H” level when enabled by the output control.

Power up / down Characteristics



Package Dimensions

As of July, 2001  
Unit: mm



\*Pd plating

Hitachi Code	TTP-48DBV
JEDEC	—
JEITA	—
Mass (reference value)	0.20 g

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